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12-OUTPUT LOW POWER DIFFERENTIAL BUFFER FOR PCIE GEN3 AND QPI 9ZXL1230

General Description

The 9ZXL1230 is a small-footprint, low power 12-output differential buffer that meets all the performance requirements of the Intel DB1900Z specification. It is pin compatible to the 9ZX21200. The 9ZXL1230 is backwards compatible to PCIe Gen2 and QPI 6.4GT/s specifications. A fixed, internal feedback path maintains low drift for critical QPI applications.

Recommended Application

12-output Low Power PCIe Gen3/QPI differential buffer for Romley

Output Features

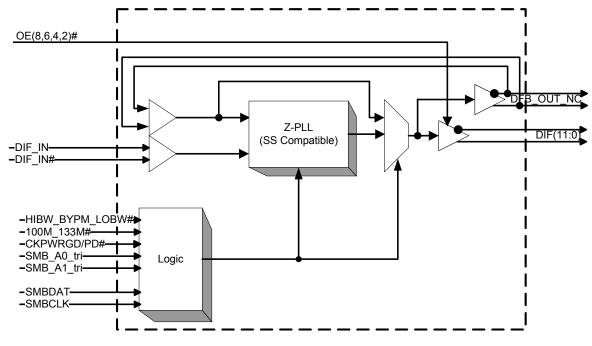
12 - 0.7V low-power HCSL-compatible output pairs

Features/Benefits

- Low-power push-pull outputs; Save power and board space no Rp
- Pin compatible to 9ZX21200; easy path to >50% power savings
- Space-saving 56-pin QFN package
- · Fixed feedback path for 0ps input-to-output delay
- 9 Selectable SMBus Addresses; Mulitple devices can share the same SMBus Segment
- 4 OE# pins; Hardware control of four outputs, other outputs free run
- PLL or bypass mode; PLL can dejitter incoming clock
- 100MHz or 133MHz PLL mode operation; supports PCIe and QPI applications
- Selectable PLL bandwidth; minimizes jitter peaking in downstream PLL's
- Spread Spectrum Compatible; tracks spreading input clock for low EMI

Key Specifications

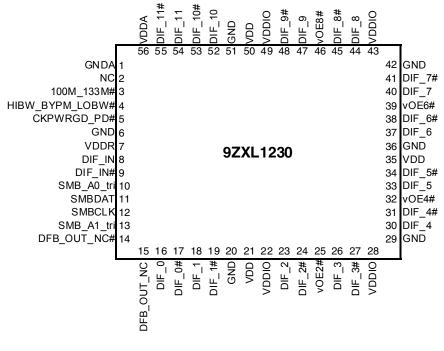
- Cycle-to-cycle jitter <50ps
- Output-to-output skew <65 ps
- Input-to-output delay variation <50ps
- PCIe Gen3 phase jitter <1.0ps RMS
- QPI 9.6GT/s 12UI phase jitter <0.2ps RMS



1

Block Diagram

Pin Configuration



Note: Pins with ^ prefix have internal 120K pullup Pins with v prefix have internal 120K pulldowm

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Power Management Table

CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	DIF(11:0)/ DIF(11:0)#	PLL STATE IF NOT IN BYPASS MODE
0	Х	Х	Low/Low	OFF
1	Running	0	Low/Low	ON
1	Hummig	1	Running	ON

Functionality at Power-up (PLL mode)

100M_133M#	DIF_IN MHz	DIF(11:0)
1	100.00	DIF_IN
0	133.33	DIF_IN

Power Connections

	Pin Number		_
VDD	VDDIO	GND	Description
56		1	Analog PLL
7		6	Analog Input
21,35,50	22,28,43,49	20,29,36,42, 51	DIF clocks

PLL Operating Mode Readback Table

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6
Low (Low BW)	0	0
Mid (Bypass)	0	1
High (High BW)	1	1

Tri-Level Input Thresholds

Level	Voltage
Low	<0.8V
Mid	1.2 <vin<1.8v< td=""></vin<1.8v<>
High	Vin > 2.2V

PLL Operating Mode

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

9ZXL1230 SMBus Addressing

Pi	n	
SMB_A1_tri	SMB_A0_tri	SMBus Address
0	0	D8
0	М	DA
0	1	DE
М	0	C2
М	М	C4
М	1	C6
1	0	CA
1	М	CC
1	1	CE

Pin Descriptions

PIN #	PIN NAME	TYPE	DESCRIPTION
1	GNDA	PWR	Ground pin for the PLL core.
2	NC	N/A	No Connection.
3	100M_133M#	IN	3.3V Input to select operating frequency
3	100101_133101#	IIN	See Functionality Table for Definition
4	HIBW_BYPM_LOBW#	IN	Trilevel input to select High BW, Bypass or Low BW mode.
-			See PLL Operating Mode Table for Details.
5	CKPWRGD_PD#	IN	Notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on
	_		subsequent assertions. Low enters Power Down Mode.
6	GND	PWR	Ground pin.
7	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and
			filtered appropriately.
8	DIF_IN	IN	0.7 V Differential TRUE input
9	DIF_IN#	IN	0.7 V Differential Complementary Input
10	SMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9
11	SMBDAT	I/O	SMBus Addresses. Data pin of SMBUS circuitry, 5V tolerant
	SMBCLK	IN	
12	SIVIBULK	lin	Clock pin of SMBUS circuitry, 5V tolerant SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9
13	SMB_A1_tri	IN	SMBus Addresses.
			Complementary half of differential feedback output, provides feedback signal to the PLL for synchronization
14	DFB_OUT_NC#	OUT	with input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback
		001	is internal to the package.
			True half of differential feedback output, provides feedback signal to the PLL for synchronization with the input
15	DFB_OUT_NC	OUT	clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal
			to the package.
16	DIF_0	OUT	0.7V differential true clock output
17	DIF_0#	OUT	0.7V differential Complementary clock output
18	DIF_1	OUT	0.7V differential true clock output
19	DIF_1#		0.7V differential Complementary clock output
20	GND		Ground pin.
21	VDD		Power supply, nominal 3.3V
	VDDIO		Power supply for differential outputs
	DIF_2		0.7V differential true clock output
24	DIF_2#	OUT	0.7V differential Complementary clock output
25	OE2#	IN	Active low input for enabling DIF pair 2.
_			1 =disable outputs, 0 = enable outputs
	DIF_3		0.7V differential true clock output
	DIF_3#		0.7V differential Complementary clock output
	VDDIO		Power supply for differential outputs
	GND		Ground pin.
	DIF_4		0.7V differential true clock output
31	DIF_4#	OUT	0.7V differential Complementary clock output

Pin Descriptions (cont.)

			-
32	OE4#	IN	Active low input for enabling DIF pair 4
_	-		1 =disable outputs, 0 = enable outputs
33	DIF_5	OUT	0.7V differential true clock output
34	DIF_5#	OUT	0.7V differential Complementary clock output
35	VDD	PWR	Power supply, nominal 3.3V
36	GND	PWR	Ground pin.
37	DIF_6	OUT	0.7V differential true clock output
38	DIF_6#	OUT	0.7V differential Complementary clock output
39	OE6#	IN	Active low input for enabling DIF pair 6.
39	020#	IIN	1 =disable outputs, 0 = enable outputs
40	DIF_7	OUT	0.7V differential true clock output
41	DIF_7#	OUT	0.7V differential Complementary clock output
42	GND	PWR	Ground pin.
43	VDDIO	PWR	Power supply for differential outputs
44	DIF_8	OUT	0.7V differential true clock output
45	DIF_8#	OUT	0.7V differential Complementary clock output
46	OE8#	IN	Active low input for enabling DIF pair 8.
40	OE0#	IIN	1 =disable outputs, 0 = enable outputs
47	DIF_9	OUT	0.7V differential true clock output
48	DIF_9#	OUT	0.7V differential Complementary clock output
49	VDDIO	PWR	Power supply for differential outputs
50	VDD	PWR	Power supply, nominal 3.3V
51	GND	PWR	Ground pin.
52	DIF_10	OUT	0.7V differential true clock output
53	DIF_10#	OUT	0.7V differential Complementary clock output
54	DIF_11	OUT	0.7V differential true clock output
55	DIF_11#	OUT	0.7V differential Complementary clock output
56	VDDA	PWR	3.3V power for the PLL core.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9ZXL1230. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDD, VDDA	VDD for core logic and PLL			4.6	V	1,2
IO Supply Voltage	VDD_IO	VDD for differential IO			4.6	V	1,2
Input Low Voltage	V _{IL}		GND-0.5			V	1
Input High Voltage	V _{IH}	Except for SMBus interface			V _{DD} +0.5V	V	1
Input High Voltage	VIHSMB	SMBus clock and data pins			5.5V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

Electrical Characteristics–DIF_IN Clock Input Parameters

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 \text{ V} \pm -5\%$, VDD_IO = 1.05 to 3.3V $\pm -5\%$

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V _{CROSS}	Cross Over Voltage	150		900	mV	1
Input Swing - DIF_IN	V _{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

²Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics–Input/Supply/Common Output Parameters

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 V + -5\%$, VDD_IO = 1.05 to 3.3V + -5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	Т _{СОМ}	Commmercial range	0		70	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V _{DD} + 0.3	V	1
Input Low Voltage	V _{IL}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	V	1
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	1
Input Current	I _{INP}	Single-ended inputs $V_{IN} = 0 V$; Inputs with internal pull-up resistors $V_{IN} = VDD$; Inputs with internal pull-down resistors	-200		200	uA	1
	F _{ibyp}	$V_{DD} = 3.3 V$, Bypass mode	33		150	MHz	2
Input Frequency	F _{ipll}	$V_{DD} = 3.3 V$, 100MHz PLL mode	90	100.00	110	MHz	2
	F _{ipll}	V _{DD} = 3.3 V, 133.33MHz PLL mode	120	133.33	147	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	CIN	Logic Inputs, except DIF_IN	1.5		5	рF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	рF	1,4
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V_{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency	f _{MODIN}	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	4		12	cycles	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of control inputs			10	ns	1,2
Trise	t _R	Rise time of control inputs			10	ns	1,2
SMBus Input Low Voltage	VILSMB				0.8	V	1
SMBus Input High Voltage	VIHSMB		2.1		V _{DDSMB}	V	1
SMBus Output Low Voltage	VOLSMB	@ I _{PULLUP}			0.4	V	1
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	1
Nominal Bus Voltage	V _{DDSMB}	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴DIF_IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics–DIF 0.7V Low Power Differential Outputs

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on	1	3.3	4	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		7	20	%	1, 2, 4
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	778	850	mV	1
Voltage Low	VLow	averaging on)	-150	0	150	ΠV	1
Max Voltage	Vmax	Measurement on single ended signal using		985	1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-91		mv	1
Vswing	Vswing	Scope averaging off	300	1556		mV	1, 2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	300	458	550	mV	1, 5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		17	140	mV	1, 6

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 \text{ V} + -5\%$, VDD_IO = 1.05 to 3.3V + -5%

¹Guaranteed by design and characterization, not 100% tested in production. $C_L = 2pF$ with $R_S = 33\Omega$ for $Zo = 50\Omega$ (100 Ω differential trace impedance).

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ -Vcross to be smaller than Vcross absolute.

Electrical Characteristics–Current Consumption

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 \text{ V} + -5\%$, VDD_IO = 1.05 to 3.3V + -5%

A 0000 - 11 J 3 -							
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	IDDVDD	133MHz, C_L = Full load; VDD rail		18	25	mA	1
Operating Current	I _{DDVDDA}	133MHz, $C_L = Full load; VDDA+VDDR rail$		16	20	mA	1
	IDDVDDIO	133MHz, C_L = Full load; VDD IO rail		101	106	mA	1
	I _{DDVDDPD}	Power Down, VDD Rail		0.01	1	mA	1
Powerdown Current	I _{DDVDDAPD}	Power Down, VDDA+VDDR Rail		3	5	mA	1
	IDDVDDIOPD	Power Down, VDD_IO Rail		0.01	0.2	mA	1

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¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics–Skew and Differential Jitter Parameters

A = 1000, 00000 = 0.00 + 1.53, 000 = 1.00 = 0.00 + 1.53, 000 = 0.00 = 0.00 + 1.53, 0000 = 0.0000 = 0.00000 = 0.0000 = 0.00000 = 0.00000 = 0.00000 = 0.00000 = 0.00000 = 0.00000 = 0.000000 = 0.00000000								
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES	
CLK_IN, DIF[x:0]	t _{SPO_PLL}	Input-to-Output Skew in PLL mode nominal value @ 25°C, 3.3V	-100	-60	100	ps	1,2,4,5,8	
CLK_IN, DIF[x:0]	t _{PD_BYP}	Input-to-Output Skew in Bypass mode nominal value @ 25°C, 3.3V	2.5	3.2	4.5	ns	1,2,3,5,8	
CLK_IN, DIF[x:0]	t _{DSPO_PLL}	Input-to-Output Skew Varation in PLL mode across voltage and temperature	-50	0	50	ps	1,2,3,5,8	
CLK_IN, DIF[x:0]	t _{DSPO_BYP}	Input-to-Output Skew Varation in Bypass mode across voltage and temperature	-250		250	ps	1,2,3,5,8	
CLK_IN, DIF[x:0]	t _{DTE}	Random Differential Tracking error beween two 9ZX devices in Hi BW Mode		3	5	ps (rms)	1,2,3,5,8	
CLK_IN, DIF[x:0]	t _{DSSTE}	Random Differential Spread Spectrum Tracking error beween two 9ZX devices in Hi BW Mode		10	75	ps	1,2,3,5,8	
DIF{x:0]	t _{SKEW_ALL}	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)		60	65	ps	1,2,3,8	
PLL Jitter Peaking	j _{peak-hibw}	LOBW#_BYPASS_HIBW = 1	0	1.2	2.5	dB	7,8	
PLL Jitter Peaking	jpeak-lobw	LOBW#_BYPASS_HIBW = 0	0	0.76	2	dB	7,8	
PLL Bandwidth	рII _{нвw}	LOBW#_BYPASS_HIBW = 1	2	3	4	MHz	8,9	
PLL Bandwidth	pll _{LOBW}	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9	
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50.1	55	%	1	
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz	-2	0	2	%	1,10	
Jitter, Cycle to cycle	t.	PLL mode		34	50	ps	1,11	
	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		17	50	ps	1,11	

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 \text{ V} + -5\%$, VDD_IO = 1.05 to 3.3V + -5%

Notes for preceding table:

¹ Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

² Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

³ All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

⁴ This parameter is deterministic for a given device

⁵ Measured with scope averaging on to find mean value.

^{6.}t is the period of the input clock

⁷ Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

^{8.} Guaranteed by design and characterization, not 100% tested in production.

⁹ Measured at 3 db down or half power point.

¹⁰ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

¹¹ Measured from differential waveform

Electrical Characteristics–Phase Jitter Parameters

 T_{A} = $T_{COM};$ Supply Voltage V_{DD} = 3.3 V +/-5%, VDD_IO = 1.05 to 3.3V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
	t _{iphPCleG1}	PCIe Gen 1		34	86	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.2	3	ps (rms)	1,2
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.2	3.1	ps (rms)	1,2
⁴ DIF_IN input	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.5	1	ps (rms)	1,2,4
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.24	0.5	ps (rms)	1,5
	t _{jphQPI_SMI}	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.14	0.3	ps (rms)	1,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.12	0.2	ps (rms)	1,5
	t _{jphPCleG1}	PCIe Gen 1		3.7	10	ps (p-p)	1,2,3
	t _{jph} PCleG2	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.1	ps (rms)	1,2,6
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.4	0.5	ps (rms)	1,2,6
	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.09	0.2	ps (rms)	1,2,4,6
	t _{jphQPI_SMI}	QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.14	0.1	ps (rms)	1,5,6
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.01	0.1	ps (rms)	1,5,6
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.01	0.1	ps (rms)	1,5,6

¹ Applies to all outputs.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ Subject to final radification by PCI SIG.

⁵ Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

⁶ For RMS figures, additive jitter is calculated by solving the following equation: (Additive jitter)² = (total jitter)² - (input jitter)²

Clock Periods–Differential Outputs with Spread Spectrum Disabled

			Measurement Window							
	Freq.	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock	Ι	
SSC OFF		-c2c jitter	-SSC Sh	- ppm L	0 ppm Period Nominal	+ ppm L	+SSC Sh	+c2c jitter	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

Clock Periods–Differential Outputs with Spread Spectrum Enabled

Г				Measurement Window							
		Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
	SSC ON	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
	DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
L	DIF	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

Notes:

¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZXL1230 itself does not contribute to ppm error.

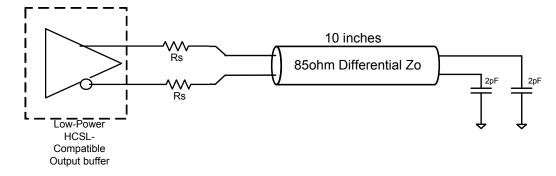
³ Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

⁴ Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode

Differential Output Terminations

DIF Zo (Ω)	Rs (Ω)
100	33
85	27

9ZXL Differential Test Loads



General SMBus Serial Interface Information for 9ZXL1230

How to Write

- · Controller (host) sends a start bit
- · Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- · Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- · Controller (host) will send a not acknowledge bit
- · Controller (host) will send a stop bit

Cor	ntroller (Host)		IDT (Slave/Receiver
T	starT bit	_	
	ave Address	_	
WR	WRite	-	
			ACK
Beginning Byte = N		-	
			ACK
RT Repeat starT			
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=>
	ACK		
		_	Beginning Byte N
	ACK	_	
		ę	0
	0	X Byte	0
0			0
0		-	
			Byte N + X - 1
N	Not acknowledge	-	
Р	stoP bit		

	Index Bl	ock \	Write Operation
Control	ler (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave	Address		
WR	WRite		
			ACK
Beginnin	g Byte = N		
			ACK
Data Byte	Count = X	_	
			ACK
Beginnir	ng Byte N		
			ACK
0		×	
0		X Byte	0
0		ē	0
			0
Byte N	l + X - 1		
			ACK
Р	stoP bit		

SMBusTable: PLL Mode, and Frequency Select Register

Byte 0 Pin #		Name	Control Function	Type	•	4	Default	
Dyte	50 PIII#	Name		туре	0		Delault	
Bit 7	3	PLL Mode 1	PLL Operating Mode Rd back 1 R See PLL Operating Mode					
Bit 6	3	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readba	Latch		
Bit 5		Reserved						
Bit 4			Reserved				0	
Bit 3		PLL_SW_EN	Enable S/W control of PLL BW	RW	HW Latch	SMBus Control	0	
Bit 2		PLL Mode 1	PLL Operating Mode 1	RW	See PLL Op	erating Mode	1	
Bit 1		PLL Mode 0	PLL Operating Mode 1 RW Readback Table			1		
Bit 0	4	100M_133M#	Frequency Select Readback			Latch		

Note: Setting bit 3 to '1' allows the user to overide the Latch value from pin 5 via use of bits 2 and 1. Use the values from the PLL Operating Mode Readback Table. Note that Bits 7 and 6 will keep the value originally latched on pin 5. A warm reset of the system will have to accomplished if the user changes these bits.

SMBusTable: Output Control Register

Byte	1 Pin#	Name	Control Function	Туре	0	1	Default
Bit 7	42/41	DIF_7_En	Output Control overrides OE# pin	RW			1
Bit 6	38/37	DIF_6_En	Output Control overrides OE# pin	RW			1
Bit 5	34/35	DIF_5_En	Output Control overrides OE# pin	RW			1
Bit 4	30/29	DIF_4_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 3	25/26	DIF_3_En	Output Control	RW	LOW/LOW	Enable	1
Bit 2	23/24	DIF_2_En	Output Control	RW			1
Bit 1	18/19	DIF_1_En	Output Control	RW]		1
Bit 0	16/17	DIF_0_En	Output Control	RW			1

SMBusTable: Output Control Register

Byte 2	2 Pin #	Name	Control Function	Туре	0	1	Default			
Bit 7			Reserved				0			
Bit 6			Reserved							
Bit 5			Reserved							
Bit 4			Reserved							
Bit 3	55/54	DIF_11_En	Output Control	RW			1			
Bit 2	53/52	DIF_10_En	Output Control	RW		Enable	1			
Bit 1	48/47	DIF_9_En	Output Control	RW	Low/Low	Enable	1			
Bit 0	46/45	DIF_8_En	Output Control	RW			1			

SMBusTable: Reserved Register

Byte 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				0	
Bit 6		Reserved				0	
Bit 5			Reserved				0
Bit 4			Reserved				0
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

SMBusTable: Reserved Register

Byte 4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4			Reserved				0
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

SMBusTable: Vendor & Revision ID Register

Byte 5	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	RID3		R			Х
Bit 6	-	RID2		R			Х
Bit 5	-	RID1		R	A rev = 0000	Х	
Bit 4	-	R ID0		R			Х
Bit 3	-	VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID 1		R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	Γ	Device ID 7 (MSB)	R		•	1
Bit 6	-		Device ID 6	R			1
Bit 5	-		Device ID 5	R			1
Bit 4	-		Device ID 4	R	1230 is 2	30 Decimal	0
Bit 3	-		Device ID 3	R	or E	6 Hex	0
Bit 2	-		Device ID 2	R			1
Bit 1	-		Device ID 1	R			1
Bit 0	-		Device ID 0	R			0

SMBusTable: Byte Count Register

Byte	7 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4	-	BC4		RW			0
Bit 3	-	BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1
Bit 2	-	BC2	many bytes will be read back.	RW	bytes (0 to 8) v	vill be read back	0
Bit 1	-	BC1	many bytes will be read back.	RW	by d	efault.	0
Bit 0	-	BC0		RW	l í		0

SMBusTable: Reserved Register

Byte	8	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				
Bit 6				Reserved				0
Bit 5				Reserved				0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0

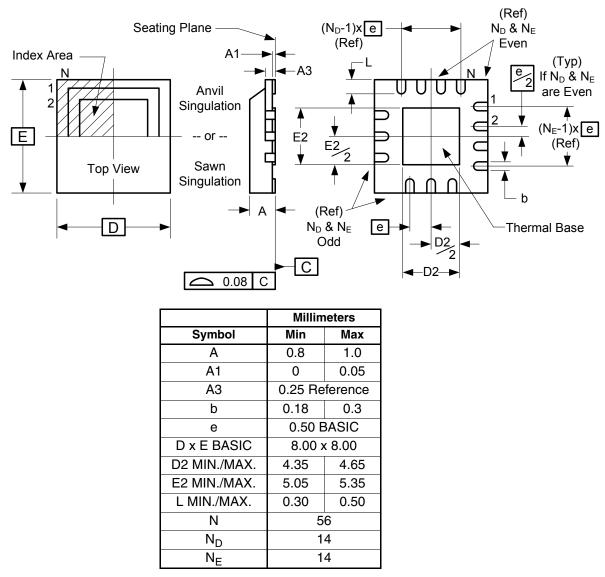
Marking Diagram



Notes:

- 1. 'LOT" is the lot number.
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3. "L" denotes RoHS compliant package.
- 4. 'COO" denotes country of origin.

Package Outline and Package Dimensions (56-pin MLF)



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
9ZXL1230AKLF	see page 15	Trays	56-pin MLF	0 to +70° C
9ZXL1230AKLFT		Tape and Reel	56-pin MLF	0 to +70° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

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Revision History

Rev.	Issuer	Issue Date	Description	Page #
А	RDW	12/8/2011	 Changed Output Features description Corrected Title of SMBus Addressing Table Updated tDSPO_BYP to +/-250ps and all Electrical tables with typical values. IDD specs revised downward. Updated Differential Test Loads Figure to indicate impedance and trace length. Removed SMBus Address info on page 12, SMBus address is selectable as indicated on page 3. Mark spec added. Move to final 	1,3,6- 10,11, 12,15
В	RDW	4/11/2012	1. Updated VDD and VDDIO pin numbers in the Power Connections Table, pinout is correct.	2
С	RDW	11/20/2015	 Updated QPI references to QPI/UPI Updated DIF_IN table to match PCI SIG specification, no silicon change 	1,6

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